

Vishay Siliconix

Automotive N-Channel 30 V (D-S) 175 °C MOSFET

DESCRIPTION

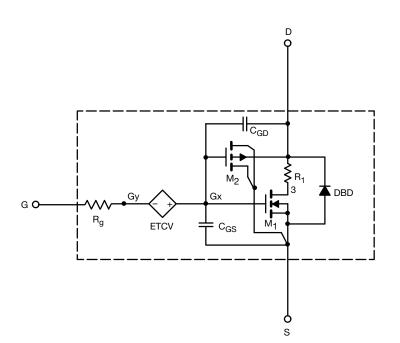
The attached SPICE model describes the typical electrical characteristics of the n-channel vertical DMOS. The subcircuit model is extracted and optimized over -55 °C to +125 °C temperature ranges under the pulsed 0 V to 10 V gate drive. The saturated output impedance is best fit at the gate bias near the threshold voltage.

A novel gate-to-drain feedback capacitance network is used to model the gate charge characteristics while avoiding convergence difficulties of the switched C_{gd} model. All model parameter values are optimized to provide a best fit to the measured electrical data and are not intended as an exact physical interpretation of the device.

CHARACTERISTICS

- N-channel vertical DMOS
- Macro model (subcircuit model)
- Level 3 MOS
- · Apply for both linear and switching application
- Accurate over -55 °C to +125 °C temperature range
- Model the gate charge

SUBCIRCUIT MODEL SCHEMATIC



Note

• This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits



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| SPECIFICATIONS (T _J = 25 °C, unless otherwise noted) | | | | | |
|--|---------------------|--|-------------------|------------------|------|
| PARAMETER | SYMBOL | TEST CONDITIONS | SIMULATED DATA | MEASURED DATA | UNIT |
| Static | | | | | |
| Gate-source threshold voltage | V _{GS(th)} | $V_{DS}=V_{GS},\ I_{D}=250\ \mu A$ | 2 | 2 | V |
| Drain-source on-state resistance ^a | R _{DS(on)} | V_{GS} = 10 V, I_D = 40 A | 0.00110 | 0.00110 | Ω |
| | | $V_{GS} = 4.5 \text{ V}, \text{ I}_{D} = 35 \text{ A}$ | 0.00140 | 0.00143 | |
| Forward transconductance a | 9 _{fs} | $V_{DS} = 15 \text{ V}, \text{ I}_{D} = 40 \text{ A}$ | 320 | 233 | S |
| Diode forward voltage | V _{SD} | I _F = 60 A | 0.72 | 0.80 | V |
| Dynamic ^b | | | | | |
| Input capacitance | C _{iss} | V _{DS} = 15 V, V _{GS} = 0 V, f = 1 MHz | 17 200 | 20 090 | pF |
| Output capacitance | C _{oss} | | 7210 | 7000 | |
| Reverse transfer capacitance | C _{rss} | | 488 | 540 | |
| Total gate charge | Qg | V_{DS} = 15 V, V_{GS} = 10 V, I_{D} = 50 A | 306 | 295 | nC |
| Gate-source charge | Q _{gs} | | 42 | 59 | |
| Gate-drain charge | Q _{gd} | | 60 | 59 | |

Notes

a. Pulse test; pulse width $\leq 300~\mu s,~duty~cycle \leq 2~\%$

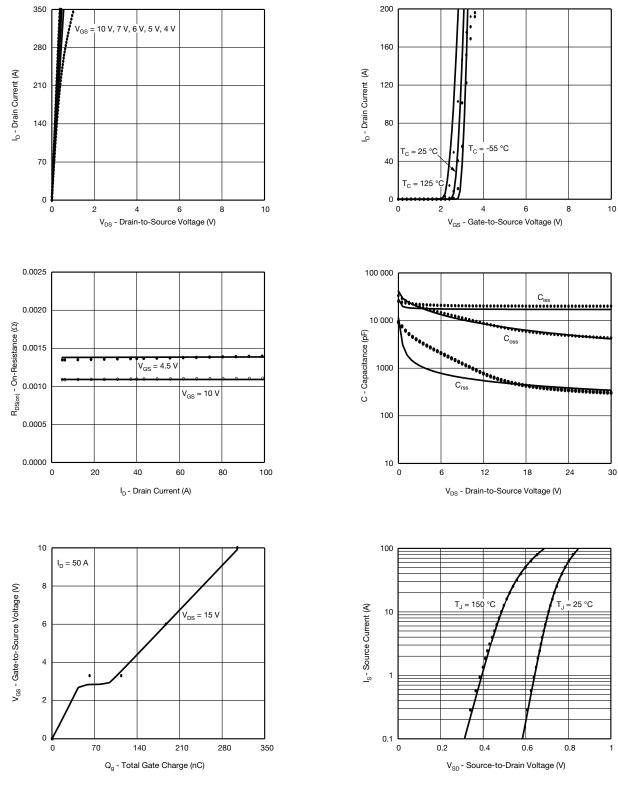
b. Guaranteed by design, not subject to production testing

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COMPARISON OF MODEL WITH MEASURED DATA (T_J = 25 °C, unless otherwise noted)



Note

Dots and squares represent measured data
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